## NSN 5961-00-088-9350

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**Inclosure Material:** 

Metal

**Overall Length:** 

0.390 inches

## **Overall Diameter:**

0.370 inches

## **Mounting Facility Quantity:**

1

## Internal Configuration:

Junction contact

## Electrode Internally-electrically Connected To Case:

Collector

#### **Mounting Method:**

Threaded stud

## Features Provided:

## Hermetically sealed case

## **Overall Width Across Flats:**

0.250 inches

## Thread Size:

0.164 inches

## Semiconductor Material:

Germanium

## Voltage Rating In Volts Per Characteristic:

40.0 breakdown voltage, collector-to-base, emitter open and 25.0 breakdown voltage, collector-to-emitter, base open and 4.0 breakdown voltage, emitter-to-base, collector open

## **Current Rating Per Characteristic:**

500.00 milliamperes source cutoff current

## **Power Rating Per Characteristic:**

500.0 milliwatts small-signal input power, common-collector

## Maximum Operating Tempurature Per Measurement Point:

100.0 degrees celsius junction

## **Special Features:**

Junction pattern arrangement: pnp

## **Thread Series Designator:**

Unc

## **Terminal Type And Quantity:**

3 uninsulated wire lead

#### **Specification Data:**

80131-release3362 professional/industrial association specification

#### Shelf Life:

N/a

#### Unit Of Measure:

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Demilitarization:

No

Fiig:

A110a0

